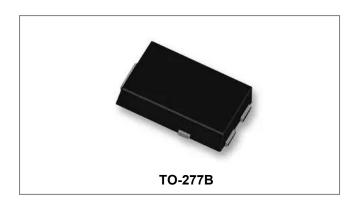






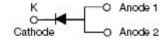
### ST1045S SCHOTTKY RECTIFIER



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Terminals finish: 100% Pure Tin
- This is a Halogen Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =80°C, rectangular wave form	10	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	<ul><li>@ 5A, Pulse, T<sub>J</sub> = 25 °C</li><li>@ 10A, Pulse, T<sub>J</sub> = 25 °C</li></ul>	0.43 0.49	0.51 0.57	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125 °C @ 10A, Pulse, T <sub>J</sub> = 125 °C	0.32 0.41	0.43 0.50	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.017	0.80	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	15	100	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	656	-	pF

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

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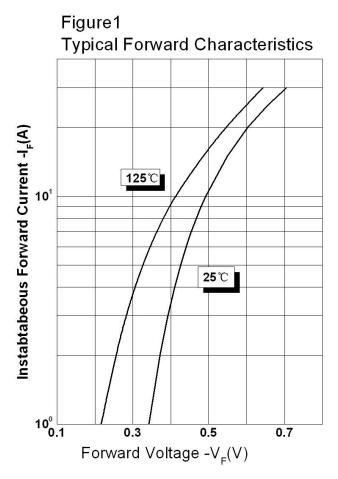


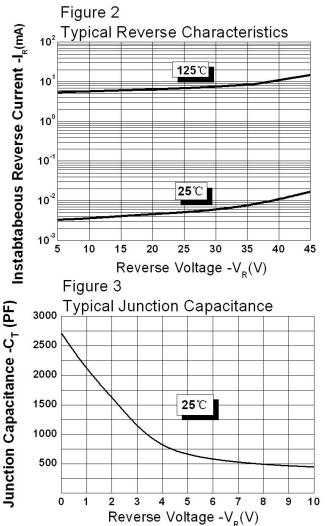


## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +150	°C
Storage Temperature	$T_{stg}$	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ heta JC}$	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

# **Ratings and Characteristics Curves**





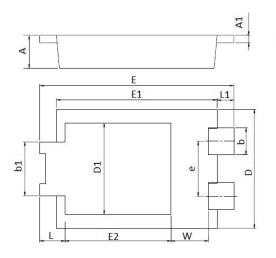
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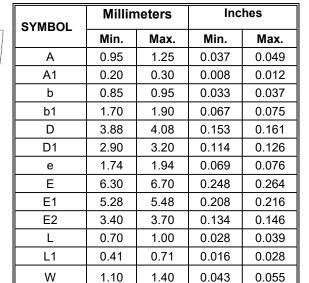




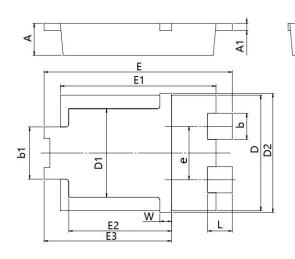


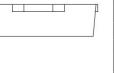
### **Mechanical Dimensions TO-277B**





#### **Mechanical Dimensions TO-277B(New)**





SYMBOL	Millimeters		Inches		
STWIBOL	Min.	Max.	Min.	Max.	
Α	0.95	1.25	0.037	0.049	
A1	0.20	0.30	0.008	0.012	
b	0.85	0.95	0.033	0.037	
b1	1.70	1.90	0.067	0.075	
D	3.88	4.08	0.153	0.161	
D1	2.90	3.20	0.114	0.126	
D2	4.25	-	0.167	-	
е	1.74	1.94	0.069	0.076	
E	6.30	6.70	0.248	0.264	
E1	5.28	5.48	0.208	0.216	
E2	3.40	3.70	0.134	0.146	
E3	4.20	4.60	0.165	0.181	
L	0.65	1.05	0.025	0.041	
W	0.25	0.55	0.010	0.022	

Notes: New Mechanical Dimensions is performed from date code 2236X.

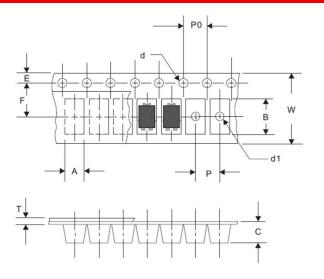
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### **Carrier Tape Specification TO-277B**



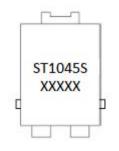
SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

### **Ordering Information**

Device	Package	Shipping
ST1045S	TO-277B(Pb-Free)	5000pcs/ reel
ST1045STR	TO-277B(Pb-Free)	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



Where XXXXX is YYWWL

ST = Device Type
10 = Forward Current (10A)
45 = Reverse Voltage (45V)
S = Package type
YY = Year
WW = Week

L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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